

Exploration of the helimagnetic and skyrmion lattice phase diagram in Cu_2OSeO_3 using magnetoelectric susceptibility

A. A. Omrani,¹ J. S. White,^{1,2} K. Prša,¹ I. Živković,³ H. Berger,⁴ A. Magrez,⁴ Ye-Hua Liu,⁵ J. H. Han,^{6,7} and H. M. Rønnow^{1,*}

¹Laboratory for Quantum Magnetism, Ecole Polytechnique Fédérale de Lausanne (EPFL), CH-1015 Lausanne, Switzerland

²Laboratory for Neutron Scattering, Paul Scherrer Institut, CH-5232 Villigen, Switzerland

³Institute of Physics, Bijenička 46, HR-10000 Zagreb, Croatia

⁴Crystal Growth Facility, Ecole Polytechnique Fédérale de Lausanne (EPFL), CH-1015 Lausanne, Switzerland

⁵Zhejiang Institute of Modern Physics and Department of Physics, Zhejiang University, Hangzhou 310027, People's Republic of China

⁶Department of Physics and BK21 Physics Research Division, Sungkyunkwan University, Suwon 440-746, Korea

⁷Asia Pacific Center for Theoretical Physics, Pohang, Gyeongbuk 790-784, Korea

(Received 12 September 2013; revised manuscript received 17 January 2014; published 10 February 2014)

Using superconducting quantum interference device magnetometry techniques, we have studied the change in magnetization versus applied ac electric field, i.e. the magnetoelectric (ME) susceptibility dM/dE , in the chiral-lattice ME insulator Cu_2OSeO_3 . Measurements of the dM/dE response provide a sensitive and efficient probe of the magnetic phase diagram, and we observe clearly distinct responses for the different magnetic phases, including the skyrmion lattice phase. By combining our results with theoretical calculation, we estimate quantitatively the ME coupling strength as $\lambda = 0.0146 \text{ meV}/(\text{V}/\text{nm})$ in the conical phase. Our study demonstrates the ME susceptibility to be a powerful, sensitive, and efficient technique for both characterizing and discovering new multiferroic materials and phases.

DOI: [10.1103/PhysRevB.89.064406](https://doi.org/10.1103/PhysRevB.89.064406)

PACS number(s): 75.25.-j, 75.50.Gg, 75.85.+t, 77.80.-e

Multiferroic and magnetoelectric (ME) materials that display directly coupled magnetic and electric properties may lie at the heart of new and efficient applications. Two intensely studied prototypical ME compounds with spiral order are TbMnO_3 [1,2] and $\text{Ni}_3\text{V}_2\text{O}_8$ [3], for which the microscopic mechanisms proposed to explain the generation of the electric polarization include the inverse Dzyaloshinskii-Moriya (DM) [4] and spin current [5] models, respectively.

Another exciting group of ME materials are chiral-lattice systems, since interactions that may promote symmetry-breaking magnetic order do not cancel when evaluated over the unit cell. The decisive role of noncentrosymmetry has been most clearly exemplified in itinerant MnSi [6,7], FeGe [8] and semiconducting $\text{Fe}_{1-x}\text{Co}_x\text{Si}$ [9]. In these compounds the principal phases are; (i) multiple q -domain helimagnetic order (helical phase) for $0 < B < B_{c1}(T)$, (ii) single- q helimagnetic order modulated along the field (conical phase) for $B_{c1}(T) < B < B_{c2}(T)$, and (iii) a small phase pocket close to T_N where a novel triple- q state described by three coupled helices ($\sum_i \mathbf{q}_i = 0$) is stabilized, and which corresponds to a lattice of skyrmions. This latter phase is particularly interesting, since in MnSi the nanosized ($\geq 15 \text{ nm}$) [10] skyrmions can be coherently manipulated by the conduction electrons of an applied current [7], leading to both emergent electrodynamics, [11] and promise for applications.

Most recently, the first skyrmion lattice (SkL) phase in an insulating material was discovered in the chiral-lattice material Cu_2OSeO_3 [12–14]. In direct analogy with the metallike SkL compounds, Cu_2OSeO_3 also has the chiral-cubic $P2_13$ space group, and the magnetic phase diagram is similarly composed of helical, conical, and SkL phases [12,13]. The earlier proposed ferrimagnetic state

in this compound exists for fields $B > B_{c2}(T)$ [15–17]. The discovery at lower fields that Cu_2OSeO_3 displays the seemingly generic magnetic phase diagram of a SkL compound is enthralling since a variety of studies show Cu_2OSeO_3 to display a ME coupling [12,15,18–21]. Indeed, the microscopic origin for the ME coupling is identified as caused by the d - p hybridization mechanism [21–24]. Most recently, emergent ME properties of the individual skyrmion particles were proposed [21,25], and demonstrated to exist experimentally [26]. Cu_2OSeO_3 represents a thus far unique opportunity for studying the electric field control of the magnetic properties of a ME SkL system.

The majority of the reported ME effects in materials are obtained from standard measurements of the electric polarization performed as a function of the applied magnetic field and temperature [12,15,19,21]. Here we report measurements of the ME susceptibility, which is the change in sample magnetization with ac electric field, to conduct a highly sensitive exploration of the ME effect across the entire magnetic phase diagram of Cu_2OSeO_3 . While a similar approach has been applied previously for exploring the ME effect in Cr_2O_3 [27], our study demonstrates the capability of the technique for revealing the detailed structure of the rich helimagnetic and skyrmion lattice phase diagram of Cu_2OSeO_3 . Furthermore, we obtain a quantitative estimate of the ME coupling strength by comparing our data with theoretical calculations, thus showing the potential of this technique for the efficient discovery and parametrization of new ME phases.

Single crystals of Cu_2OSeO_3 were grown by a standard chemical vapor transport method [16,20]. Our sample had a mass of 11.7 mg, a volume of $2 \times 2 \times 0.39 \text{ mm}^3$, and was cut with the thinnest dimension along the [111] direction. Electrodes were created directly on the (111) crystal faces using silver paint. The sample was then mounted

*henrik.ronnow@epfl.ch

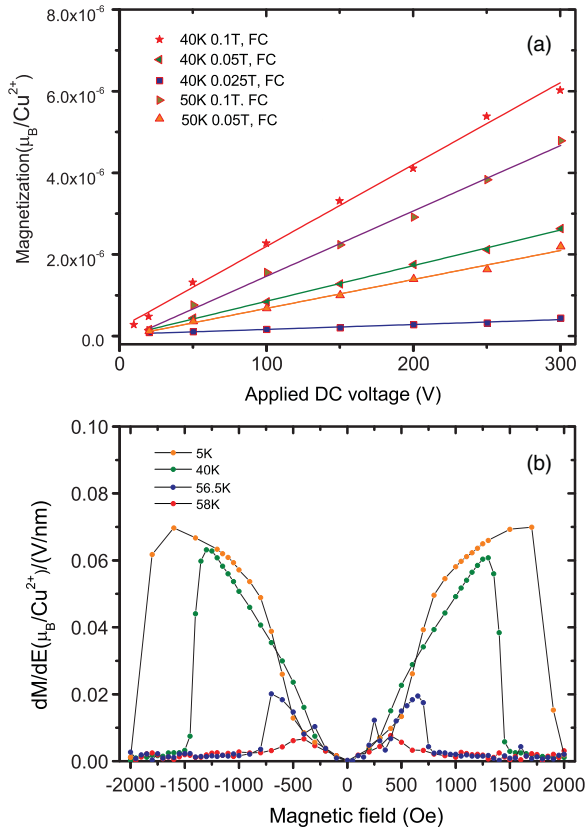


FIG. 1. (Color online) (a) ME signal as function of constant electric field applied along [111] for various magnetic field and temperature conditions, (b) magnetic field scans of the ac ME susceptibility measured at different temperatures (no demagnetization correction is applied here).

inside a vertical-field superconducting quantum interference device (SQUID) magnetometer, in which two different experimental geometries were studied: (i) $E \parallel \mu_0 H \parallel [111]$ and (ii) $E \parallel [111]$ with $\mu_0 H \parallel [1-10]$.

To measure the ME susceptibility, an ac electric field was applied to a single crystal sample and, in the presence of a simultaneous dc magnetic field, a SQUID magnetometer was used to monitor directly the associated change in sample magnetization. The change in the SQUID signal resulting from the applied ac electric field was recorded using a lock-in amplifier synchronized with the ac voltage generator. Any current-induced effects are readily ruled out due to the negligible (~ 1 nA) leakage current across the insulating sample.

The change in magnetization of the Cu_2OSeO_3 sample in the configuration of $E \parallel \mu_0 H \parallel [111]$ is shown in Fig. 1(a). We observe that the response is linear in the electric field up to 7.7×10^{-4} V/nm. Therefore, the gradient of the curve provides the change in magnetization as a function of the electric field, or the ME susceptibility, χ_{ME} , dM/dE for each magnetic field and temperature, and we can expect to model the phenomena with linear response theories and, for example a Ginzburg-Landau phenomenology [28]. For the example of the (field-cooled) data at $\mu_0 H = 0.1$ T and $T = 40$ K, this variation is 6.6×10^{-8} μ_B/Cu per 1 V/m. In Fig. 1(b), the magnetic field dependence of dM/dE is presented at various

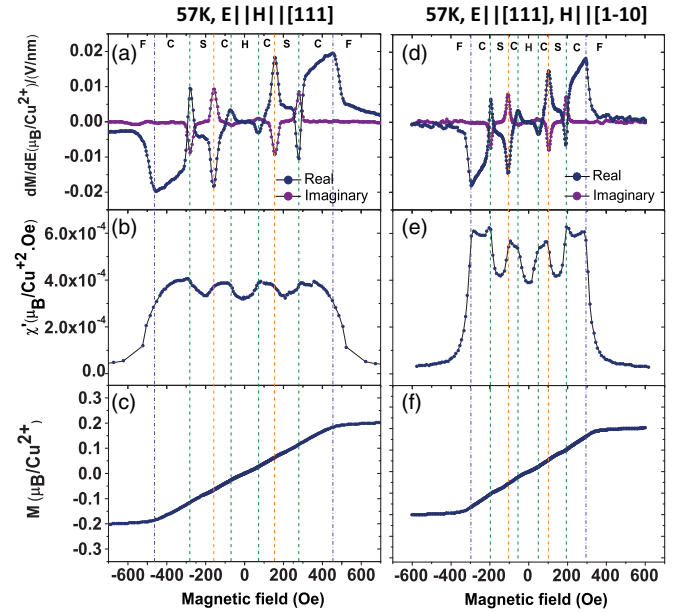


FIG. 2. (Color online) The magnetic field dependence of: (a), (d) the ac ME susceptibility; (b), (e) ac magnetic susceptibility; and (c), (f) dc magnetization for $E \parallel \mu_0 H \parallel [111]$ (a)–(c), and $E \parallel [111]$ with $\mu_0 H \parallel [1-10]$ (d)–(f). In the latter crystal orientation, due to the small area exposed to magnetic field, no demagnetization correction has been made. All measurements of dM/dE were done using a 10 Hz, 5 V ac voltage. The letters F, C, S, and H denote the ferrimagnetic, conical, skyrmion, and helical phases, respectively.

temperatures, covering the helical, conical and ferrimagnetic phases. Salient features include the linear tendency of dM/dE of different slopes within the conical phase, and the drop of the signal for fields $B > B_{c2}(T)$ in the ferrimagnetic phase.

Since the SkL phase is reported to exist in the approximate temperature range of 56–58 K, in Fig. 2 we show high-precision magnetic-field-dependent measurements of the ac ME and magnetic susceptibilities, and the dc magnetization at $T = 57$ K for the two different experimental configurations $E \parallel \mu_0 H \parallel [111]$ [Figs. 2(a)–2(c)] and $E \parallel [111]$ with $\mu_0 H \parallel [1-10]$ [Figs. 2(d)–2(f)]. The ME susceptibility is seen to be a particularly revealing probe of the magnetic phase diagram; a series of sharp peaks and dips are observed in both the real and imaginary parts that give clear evidence for magnetic transitions. A remarkable feature of these data is the high precision at which these transitions may be determined, compared to the corresponding kinklike features in the ac magnetic susceptibility [Figs. 2(b) and 2(e)], and only small wiggles seen in the dc magnetization [Figs. 2(c) and 2(f)].

For both magnetic field geometries, the magnetic field dependence of the ME susceptibility can be divided into three main parts. First, the value of dM/dE remains very small in the helical phase and seemingly constant in SkL phases. Second, dM/dE depends linearly on the applied magnetic field within the conical phase on both sides of the skyrmion phase. This is most easily seen in the high field regime, where also the maximum signal in dM/dE is observed. Third, both the lower and upper field borders between the SkL and conical phases are characterized by strong peaks and

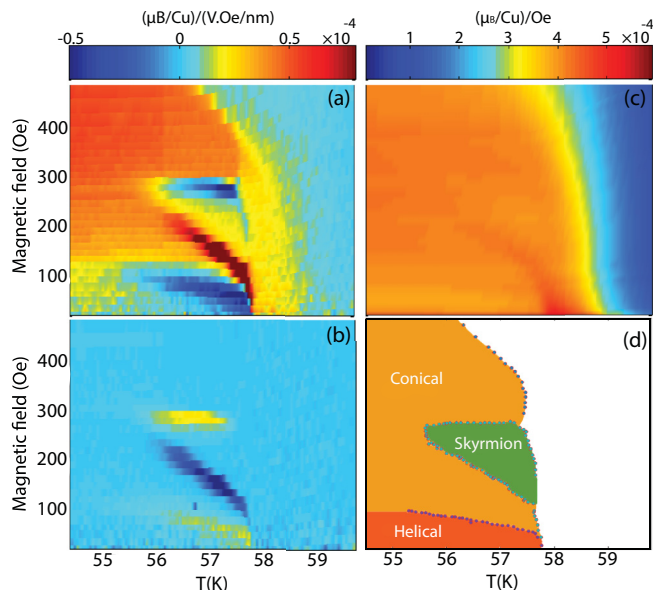


FIG. 3. (Color online) For the $E \parallel \mu_0 H \parallel [111]$ geometry, magnetic phase diagrams constructed using (a) the real, and (b) imaginary parts of the ME susceptibility $(dM/dE)/H$, and (c) the dc magnetization (M/H) . These diagrams were constructed using temperature scans (warming) after the sample was field cooled from 70 K. In (d) we show the portion of the magnetic phase diagram near the ordering temperature extracted from the real part of the temperature scans signals.

dips in both the real and imaginary parts of dM/dE . The observed peaks and dips for the transition into and out of the SkL phase reflect nonlinear responses occurring at the phase boundaries. This observation contrasts the behavior seen for the transitions at both B_{c1} (helical-conical transition), and B_{c2} (conical-ferrimagnetic transition), where only the real part of the ME susceptibility shows steps. Extra measurements were carried out at $T < 56$ K where no SkL phase is expected, and only the transitions at $B_{c1}(T)$ and $B_{c2}(T)$ are observed. This confirms that the extra peaks and dips observed at $T = 57$ K may be assigned to transitions on the borders of the SkL phase.

The magnetic field and temperature dependence of the real and imaginary parts of dM/dE , and the dc magnetization are shown for the $E \parallel \mu_0 H \parallel [111]$ geometry in Figs. 3(a)–3(c). By tracking the peak and dip features observed in temperature scans of dM/dE , the main magnetic phases are easily identified (particularly in the real part of dM/dE), and agree well with the phase diagram determined with alternative methods [12,13]. The data shown in Fig. 3(b) also indicate that the large peaks and dips in the imaginary part of dM/dE occur at the SkL phase boundary. In Fig. 3(d) the first magnetic phase diagram constructed by using the ac ME susceptibility technique is presented. Only weak traces of these transitions are seen in the phase diagram produced by dc magnetization [Fig. 3(c)]. Above 58 K the continuous decay of the signal with increasing temperature indicates a regime of short-range order. The field dependence in this regime is linear with slope of similar magnitude as in the conical phase and there are no signs of crossovers. We therefore conclude that the critical

fluctuations are short-range correlations of the conical order type.

Next we develop a theoretical framework for calculating χ_{ME} (for details, see Liu *et al.* [29]). We consider the effective Hamiltonian $\mathcal{H} = \mathcal{H}_{HDM} + \mathcal{H}_{ME}$ which approximates the microscopic Hamiltonian of the system with a simplified one where one effective magnetic moment \mathbf{S}_i represents the total unit-cell moment in Cu_2OSeO_3 [30]. The first term $\mathcal{H}_{HDM} = \sum_{i,j} (-J\mathbf{S}_i \cdot \mathbf{S}_j - D \cdot \mathbf{S}_i \times \mathbf{S}_j) - \sum_i \mathbf{B} \cdot \mathbf{S}_i$, respectively includes Heisenberg and Dzyaloshinskii-Moriya (DM) spin-spin interactions, and the Zeeman term. [25] The second term $\mathcal{H}_{ME} = -\sum_i \mathbf{P}_i \cdot \mathbf{E}_i$ includes the ME coupling where the local electric dipole moment per unit cell is coupled to the spin configuration according to Refs. [21,25]

$$\mathbf{P}_i = \lambda (S_i^y S_i^z, S_i^z S_i^x, S_i^x S_i^y). \quad (1)$$

The coupling constant λ here represents the strength of the ME coupling between the effective unit cell moments and the electric field. If the direction of the applied electric field is $\hat{\mathbf{e}}$ and we are interested in the magnetization along $\hat{\mathbf{m}}$, the ME susceptibility is obtained from

$$\chi_{ME} = \frac{\partial(\mathbf{M} \cdot \hat{\mathbf{m}})}{\partial E} = \frac{g\mu_B}{NT} \left(\left\langle \left[\sum_i \mathbf{S}_i \cdot \hat{\mathbf{m}} \right] \left[\sum_i \mathbf{P}_i \cdot \hat{\mathbf{e}} \right] \right\rangle - \left\langle \sum_i \mathbf{S}_i \cdot \hat{\mathbf{m}} \right\rangle \left\langle \sum_i \mathbf{P}_i \cdot \hat{\mathbf{e}} \right\rangle \right), \quad (2)$$

where λ has been absorbed into E so that this term has dimensions of energy, the magnetization is $\mathbf{M} = g\mu_B(\sum_i \mathbf{S}_i)/N$, and N is the number of unit cells (in our simulation $N = 12^3$) and T is the temperature. The averages $\langle \dots \rangle$ are performed by means of Monte Carlo simulation. For the case of $B \parallel E \parallel [111]$, we can choose $\hat{\mathbf{e}} = \hat{\mathbf{m}} = (111)/\sqrt{3}$. The results of these calculations are shown in Fig. 4(b).

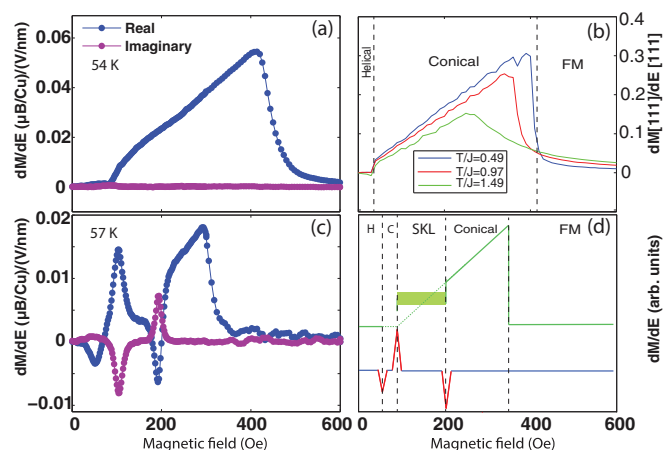


FIG. 4. (Color online) Real and imaginary part of the ME response for the $E \parallel [111]$ with $\mu_0 H \parallel [1-10]$ geometry at 54 K (a) and 57 K (c), respectively. Part (b) represents the simulation results of a 3D lattice hosting helical, conical, and ferrimagnetic phases in the $E \parallel \mu_0 H \parallel [111]$ geometry. In (d) a schematic of the piecewise linear behavior of dM/dE in the conical phase, and also including peaks and dips on each side of the SkL phase.

Additionally, a separate Ginzburg-Landau (GL) approach is developed to derive the linear ME response in the conical phase. In the same geometry as introduced above, the full GL free energy density has the form:

$$\begin{aligned} \mathcal{F} = & \frac{J}{2a}(\nabla\boldsymbol{\mu})^2 + \frac{D}{a^2}\boldsymbol{\mu} \cdot (\nabla \times \boldsymbol{\mu}) \\ & - n|\mathbf{S}|\frac{B}{a^3}(\mu_x + \mu_y + \mu_z)/\sqrt{3} \\ & - \lambda\frac{E}{a^3}(\mu_y\mu_z + \mu_z\mu_x + \mu_x\mu_y)/\sqrt{3}, \end{aligned} \quad (3)$$

where $\boldsymbol{\mu}$ is the sample magnetization, J , D , n , and a are the Heisenberg, DM coupling energies, number of Cu sites in the unit cell, and lattice constants, respectively. After a rotation of both real and spin coordinates [25], the [111] direction lies along the z axis in the rotated frame and Eq. (3) becomes

$$\frac{\mathcal{F}}{8JK^2} = (\nabla\boldsymbol{\mu})^2 + \boldsymbol{\mu} \cdot (\nabla \times \boldsymbol{\mu}) - \beta\mu_z - \frac{1}{2}\epsilon\mu_z^2, \quad (4)$$

where $\beta = n|\mathbf{S}|B/(8JK^2a^3)$ and $\epsilon = \sqrt{3}\lambda E/(8JK^2a^3)$, and the space coordinates are re-scaled as $r \rightarrow r/(4\kappa)$ with $\kappa = D/(2J)$. The dimensionless free energy in Eq. (4) facilitates the following discussion. The right-handed conical unit-length spin configuration in a three-dimensional (3D) material, which is compatible with $D > 0$, is described by

$$\boldsymbol{\mu}(x, y, z) = [\sin(\theta)\cos(qz), \sin(\theta)\sin(qz), \cos(\theta)], \quad (5)$$

where $|\boldsymbol{\mu}| = 1$, θ is the conical angle, and $(0, 0, q)$ is the conical modulation vector. By inserting (5) into the energy functional of Eq. (4), and minimizing with respect to both q and θ , we get $q_0 = 1/2$ and $\cos(\theta_0) = 2\beta/(1 - 2\epsilon)$. The derivative with respect to ϵ becomes $4\beta/[(1 - 2\epsilon)^2]$, and hence by considering the average unit cell magnetization as $|\mathbf{M}| = gn\mu_B|\mathbf{S}|$ with the same spin configuration as $\boldsymbol{\mu}$ the derivative with respect to ϵ forms as:

$$\frac{\partial(M_z)}{\partial\epsilon} = (gn\mu_B|\mathbf{S}|)\frac{4\beta}{(1 - 2\epsilon)^2}, \quad (6)$$

which depends linearly on the magnetic field. The final expression for the low electric-field limit of the ME susceptibility containing material parameters in the conical phase can be written as:

$$\begin{aligned} \chi_{\text{ME}} &= \frac{\partial(M_z)}{\partial E} = \frac{\partial(M_z)}{\partial\epsilon} \frac{\partial\epsilon}{\partial E} \\ &= 4\sqrt{3}(gn\mu_B|\mathbf{S}|)^2 \frac{\lambda}{(8JK^2)^2} B. \end{aligned} \quad (7)$$

We now discuss how our experimental results compare to the expectations of the two theoretical approaches developed. Figure 4(a) shows a magnetic field scan of dM/dE done at 54 K, which, as seen from Fig. 3, is a temperature where no SkL phase exists. At low fields, only a very small signal is observed in the helical phase. Upon increasing the field, a jump is observed in dM/dE at the transition into the conical phase, where afterward we observe a linearly increasing signal until the sharp fall upon entering the ferrimagnetic phase.

This behavior is in good qualitative agreement with the results of Monte Carlo simulations [Eq. (2)] presented in Fig. 4(b). Next we use Eq. (7) derived in the GL approach to estimate quantitatively the size of the effective ME coupling parameter λ . The slope of dM/dE extracted in the conical phase at 54 K [Fig. 4(a)] is $1.58 \times 10^{-4}(\mu_B/\text{Cu})(\text{V}/\text{nm})^{-1}(\text{Oe})^{-1}$. For Cu_2OSeO_3 the effective Heisenberg coupling between unit cell moments is chosen to be $J = 3.4$ meV, which reproduces the correct ordering temperature. The ratio $\kappa = D/2Ja = \pi/l$ is determined from the wavelength $l = 630\text{\AA}$ [13,26] of the magnetic helix relative to the lattice constant $a = 8.9\text{\AA}$ [31]. With $|\mathbf{s}| = \langle S_z \rangle$ in the ferrimagnetic phase determined to be $3.52\mu_B/\text{unit cell}$ at 54 K, we find $\lambda = 0.0146$ meV/(V/nm) = 2.34×10^{-33} J/(V/m). This value of the ME coupling leads to a local electric dipole moment per unit cell $P = 7.216 \times 10^{-27}\mu\text{C m}$ according to Eq. (1), or a macroscopic polarization $\mathbf{p} = 10.2\mu\text{C}/\text{m}^2$, which is of the same order of magnitude as reported by Seki *et al.* [12]

The observed behavior in dM/dE when passing through the SkL phase at 57 K is more complicated [Fig. 4(c)]. We interpret the signal as a contribution of a piecewise linear response and sharp nonlinear peaks at the transitions, as sketched in Fig. 4(d). Due to the strong nonlinear peaks, the exact field dependence of the response in the SkL phase cannot be determined precisely and is thus presented as a shaded green area in Fig. 4(d). The sharp peaks are ascribed to the nonlinear response related to the first-order transitions separating the conical and SkL phases. The imaginary components of the peaks have opposite sign to the real part. A possible explanation is that varying the magnetic field places the system in a higher energy out-of-equilibrium state, whereby each electric-field ac cycle releases, rather than absorbs, energy. The observation that this nonlinear effect occurs exclusively around the SkL phase borders could indicate near degeneracy of many quasiprotected nonperfect SkL configurations that couple strongly to the electric field. In turn, this provides exciting prospects for the future electric-field control of individual skyrmions.

In conclusion, we have presented a ME susceptibility study of the phase diagram and ME coupling in Cu_2OSeO_3 . By exploiting the superior sensitivity of a SQUID magnetometer, magnetization changes as small as 10^{-3} emu nm/V are detected for a 10 Hz and 5 V driving ac electric field, and allow the efficient exploration and characterization of the ME coupling across the helimagnetic phase diagram of the chiral-lattice ME Cu_2OSeO_3 . Furthermore, both Monte Carlo and Ginzburg-Landau calculations of the ME susceptibility provide a quantitative analysis of the data, as exemplified by the extraction of the ME coupling parameter $\lambda = 0.0146$ meV/(V/nm). This work demonstrates ME susceptibility measurements to be an effective technique for studying the general properties of ME compounds with rich magnetic phase diagrams, and furthermore invites new investigations of ME skyrmions, in particular their manipulation by electric field.

We gratefully acknowledge financial support from the Swiss National Science Foundation, MaNEP, and the European Research Council through the CONQUEST grant.

- [1] T. Kimura, T. Goto, H. Shintani, K. Ishizaka, T. Arima, and Y. Tokura, *Nature (London)* **426**, 55 (2003).
- [2] M. Kenzelmann, A. B. Harris, S. Jonas, C. Broholm, J. Schefer, S. B. Kim, C. L. Zhang, S.-W. Cheong, O. P. Vajk, and J. W. Lynn, *Phys. Rev. Lett.* **95**, 087206 (2005).
- [3] G. Lawes, A. B. Harris, T. Kimura, N. Rogado, R. J. Cava, A. Aharony, O. Entin-Wohlman, T. Yildirim, M. Kenzelmann, C. Broholm, and A. P. Ramirez, *Phys. Rev. Lett.* **95**, 087205 (2005).
- [4] I. A. Sergienko and E. Dagotto, *Phys. Rev. B* **73**, 094434 (2006).
- [5] H. Katsura, N. Nagaosa, and A. V. Balatsky, *Phys. Rev. Lett.* **95**, 057205 (2005).
- [6] S. Mühlbauer, B. Binz, F. Jonietz, C. Pfleiderer, A. Rosch, A. Neubauer, R. Georgii, and P. Böni, *Science* **323**, 915 (2009).
- [7] F. Jonietz, S. Mühlbauer, C. Pfleiderer, A. Neubauer, W. Münzer, A. Bauer, T. Adams, R. Georgii, P. Böni, R. A. Duine, K. Everschor, M. Garst, and A. Rosch, *Science* **330**, 1648 (2010).
- [8] X. Z. Yu, N. Kanazawa, Y. Onose, K. Kimoto, W. Z. Zhang, Y. Matsui, and Y. Tokura, *Nature Mater.* **10**, 106 (2011).
- [9] W. Münzer, A. Neubauer, T. Adams, S. Mühlbauer, C. Franz, F. Jonietz, R. Georgii, P. Böni, B. Pedersen, M. Schmidt, A. Rosch, and C. Pfleiderer, *Phys. Rev. B* **81**, 041203(R) (2010).
- [10] A. Tonomura, X. Yu, K. Yanagisawa, T. Matsuda, Y. Onose, N. Kanazawa, H. S. Park, and Y. Tokura, *Nano Lett.* **12**, 1673 (2010).
- [11] T. Schultz, R. Ritz, A. Bauer, M. Halder, M. Wagner, C. Franz, C. Pfleiderer, K. Everschor, M. Garst, and A. Rosch, *Nature Phys.* **8**, 301 (2012).
- [12] S. Seki, X. Z. Yu, S. Ishiwata, and Y. Tokura, *Science* **336**, 198 (2012).
- [13] T. Adams, A. Chacon, M. Wagner, A. Bauer, G. Brandl, B. Pedersen, H. Berger, P. Lemmens, and C. Pfleiderer, *Phys. Rev. Lett.* **108**, 237204 (2012).
- [14] S. Seki, J.-H. Kim, D. S. Inosov, R. Georgii, B. Keimer, S. Ishiwata, and Y. Tokura, *Phys. Rev. B* **85**, 220406 (2012).
- [15] J.-W. G. Bos, C. V. Colin, and T. T. M. Palstra, *Phys. Rev. B* **78**, 094416 (2008).
- [16] M. Belesi, I. Rousochatzakis, H. C. Wu, H. Berger, I. V. Shvets, F. Mila, and J.-P. Ansermet, *Phys. Rev. B* **82**, 094422 (2010).
- [17] I. Živković, D. Pajić, T. Ivek, and H. Berger, *Phys. Rev. B* **85**, 224402 (2012).
- [18] A. Maisuradze, A. Shengelaya, H. Berger, D. M. Djokić, and H. Keller, *Phys. Rev. Lett.* **108**, 247211 (2012).
- [19] M. Belesi, I. Rousochatzakis, M. Abid, U. K. Rößler, H. Berger, and J.-P. Ansermet, *Phys. Rev. B* **85**, 224413 (2012).
- [20] A. Maisuradze, Z. Guguchia, B. Graneli, H. M. Rønnow, H. Berger, and H. Keller, *Phys. Rev. B* **84**, 064433 (2011).
- [21] S. Seki, S. Ishiwata, and Y. Tokura, *Phys. Rev. B* **86**, 060403(R) (2012).
- [22] C. Jia, S. Onoda, N. Nagaosa, and J. H. Han, *Phys. Rev. B* **74**, 224444 (2006).
- [23] C. Jia, S. Onoda, N. Nagaosa, and J. H. Han, *Phys. Rev. B* **76**, 144424 (2007).
- [24] T. Arima, *J. Phys. Soc. Jpn.* **76**, 073702 (2007).
- [25] Y.-H. Liu, Y.-Q. Li, and J. H. Han, *Phys. Rev. B* **87**, 100402 (2013).
- [26] J. S. White, I. Levatić, A. A. Omrani, N. Egetenmeyer, K. Prša, I. Živković, J. L. Gavilano, J. Kohlbrecher, M. Bartkowiak, H. Berger, and H. M. Rønnow, *J. Phys.: Condens. Matter* **24**, 432201 (2012).
- [27] P. Borisov, A. Hochstrat, V. V. Shvartsman, and W. Kleeman, *Rev. Sci. Instrum.* **78**, 106105 (2007).
- [28] M. Fiebig, *J. Phys. D: Appl. Phys.* **38**, R123 (2005).
- [29] Y.-H. Liu, J. H. Han, A. A. Omrani, H. M. Rønnow, and Y.-Q. Li, [arXiv:1310.5293](https://arxiv.org/abs/1310.5293).
- [30] S. D. Yi, S. Onoda, N. Nagaosa, and J. H. Han, *Phys. Rev. B* **80**, 054416 (2009).
- [31] H. Effenberger and F. Pertlik, *Monatsch. Chem.* **117**, 887 (1986).